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REVISION HISTORY

5/14—Rev. A to Rev. B

Changes to Adding Hysteresis Section and Added Figure 32;
Renumbered Sequentially..... 11

3/11—Rev. 0 to Rev. A

Changes to Features Section..... 1
Changes to Adding Hysteresis Section

2/07—Revision 0: Initial Version

SPECIFICATIONS

$V_{DD} = 1.7\text{ V to } 5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, unless otherwise noted.

Table 1.

| Parameter | Min | Typ | Max | Unit | Test Conditions/Comments |
|--|-------|-------|-------------|-------------------------|--|
| THRESHOLDS¹ | | | | | |
| Rising Input Threshold Voltage | 399.3 | 400.4 | 401.5 | mV | $V_{DD} = 3.3\text{ V}$, $T_A = 25^{\circ}\text{C}$ |
| | 391.2 | 400.4 | 407.7 | mV | $V_{DD} = 1.7\text{ V}$ |
| | 393.1 | 400.4 | 405.9 | mV | $V_{DD} = 3.3\text{ V}$ |
| | 393.1 | 400.4 | 405.8 | mV | $V_{DD} = 5.5\text{ V}$ |
| Falling Input Threshold Voltage | 381.1 | 391.1 | 400.9 | mV | $V_{DD} = 1.7\text{ V}$ |
| | 381.2 | 391.1 | 398.4 | mV | $V_{DD} = 3.3\text{ V}$ |
| | 381.0 | 391.1 | 398.2 | mV | $V_{DD} = 5.5\text{ V}$ |
| Hysteresis = $V_{TH(R)} - V_{TH(F)}$ | 2 | 9.3 | 13.5 | mV | |
| Threshold Voltage Accuracy | | | ± 0.275 | % | $T_A = 25^{\circ}\text{C}$, $V_{DD} = 3.3\text{ V}$ |
| Threshold Voltage Temperature Coefficient | | 16 | | ppm/ $^{\circ}\text{C}$ | |
| POWER SUPPLY | | | | | |
| Supply Current | | 6.5 | 9 | μA | $V_{DD} = 1.7\text{ V}$ |
| | | 7.0 | 10 | μA | $V_{DD} = 5.5\text{ V}$ |
| INPUT CHARACTERISTICS | | | | | |
| Input Bias Current | | 0.01 | 5 | nA | $V_{DD} = 1.7\text{ V}$, $V_{IN} = V_{DD}$ |
| | | 0.01 | 5 | nA | $V_{DD} = 1.7\text{ V}$, $V_{IN} = 0.1\text{ V}$ |
| OPEN-DRAIN OUTPUTS | | | | | |
| Output Low Voltage ² | | 140 | 220 | mV | $V_{DD} = 1.7\text{ V}$, $I_{OUT} = 3\text{ mA}$ |
| | | 140 | 220 | mV | $V_{DD} = 5.5\text{ V}$, $I_{OUT} = 5\text{ mA}$ |
| Output Leakage Current ³ | | 0.01 | 1 | μA | $V_{DD} = 1.7\text{ V}$, $V_{OUT} = V_{DD}$ |
| | | 0.01 | 1 | μA | $V_{DD} = 1.7\text{ V}$, $V_{OUT} = 5.5\text{ V}$ |
| DYNAMIC PERFORMANCE | | | | | |
| High-to-Low Propagation Delay ^{2,4} | | 10 | | μs | $V_{DD} = 5\text{ V}$, $V_{OL} = 400\text{ mV}$ |
| Low-to-High Propagation Delay ^{2,4} | | 8 | | μs | $V_{DD} = 5\text{ V}$, $V_{OH} = 0.9 \times V_{DD}$ |
| Output Rise time ^{2,4} | | 0.5 | | μs | $V_{DD} = 5\text{ V}$, $V_O = (0.1\text{ to } 0.9) \times V_{DD}$ |
| Output Fall time ^{2,4} | | 0.07 | | μs | $V_{DD} = 5\text{ V}$, $V_O = (0.1\text{ to } 0.9) \times V_{DD}$ |

¹ $R_L = 100\text{ k}\Omega$, $V_O = 2\text{ V}$ swing.

² 10 mV input overdrive.

³ $V_{IN} = 40\text{ mV}$ overdrive.

⁴ $R_L = 10\text{ k}\Omega$.

ABSOLUTE MAXIMUM RATINGS

Table 2.

| Parameter | Rating |
|------------------------------|-----------------|
| V _{DD} | −0.3 V to +6 V |
| IN | −0.3 V to +6 V |
| OUT, $\overline{\text{OUT}}$ | −0.3 V to +6 V |
| Operating Temperature Range | −40°C to +125°C |
| Storage Temperature Range | −65°C to +150°C |
| Lead Temperature | |
| Soldering (10 sec) | 300°C |
| Vapor Phase (60 sec) | 215°C |
| Infrared (15 sec) | 220°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

| Package Type | θ_{JA} | Unit |
|---------------|---------------|------|
| 5-Lead SOT-23 | 240 | °C/W |

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

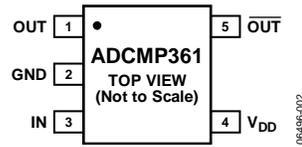


Figure 4. Pin Configuration

Table 4. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|-------------------------|--|
| 1 | OUT | Noninverting Open-Drain Output. |
| 2 | GND | Ground. |
| 3 | IN | Monitors analog input voltage on comparator. The other input of the comparator is connected to a 400 mV reference. |
| 4 | V_{DD} | Power Supply. |
| 5 | $\overline{\text{OUT}}$ | Inverting Open-Drain Output. |

TYPICAL PERFORMANCE CHARACTERISTICS

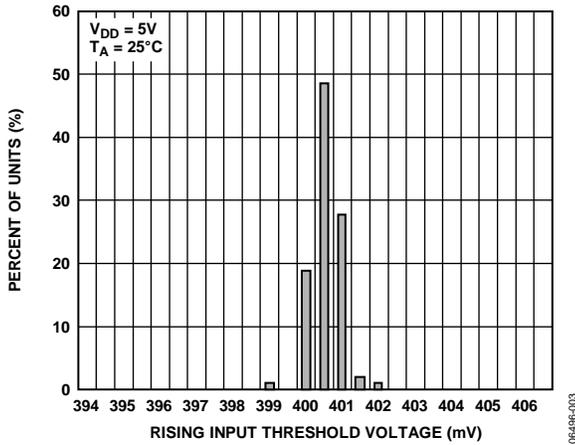


Figure 5. Distribution of Rising Input Threshold Voltage

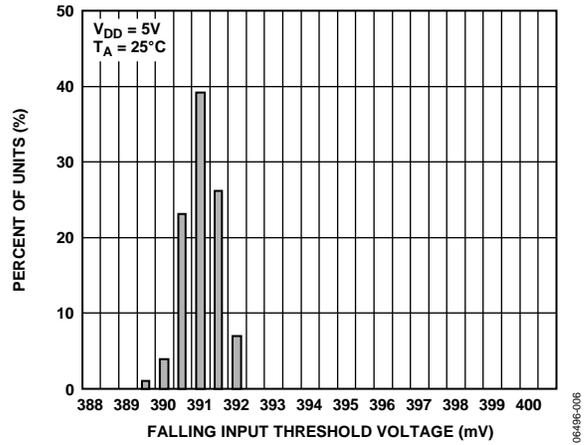


Figure 8. Distribution of Falling Input Threshold Voltage

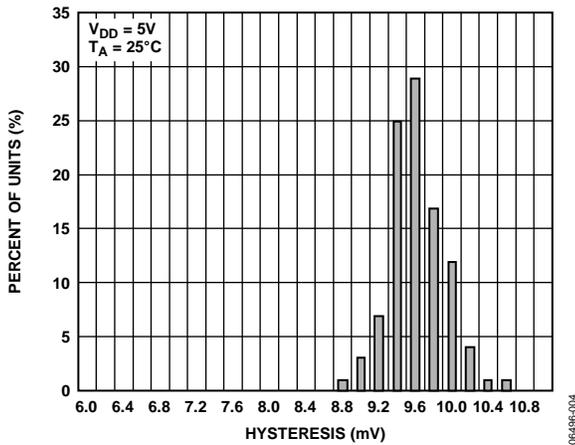


Figure 6. Distribution of Hysteresis

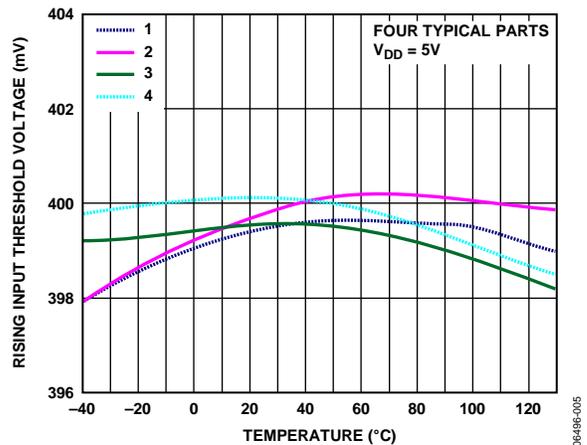


Figure 9. Rising Input Threshold Voltage vs. Temperature

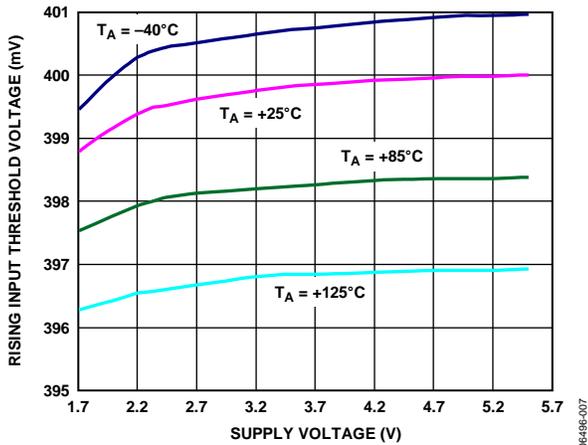


Figure 7. Rising Input Threshold Voltage vs. Supply Voltage

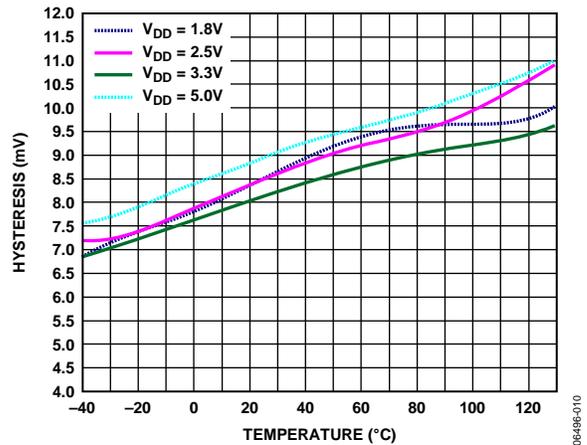


Figure 10. Hysteresis vs. Temperature

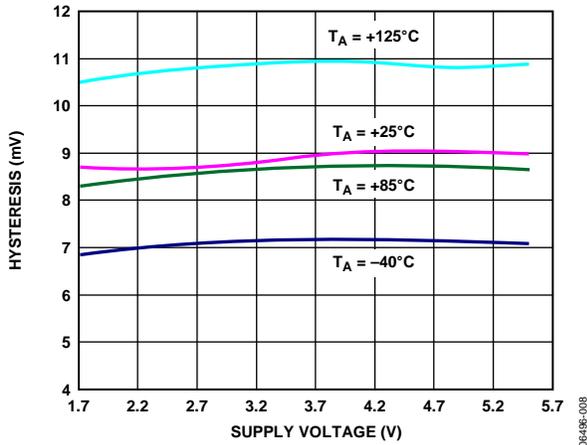


Figure 11. Hysteresis vs. Supply Voltage

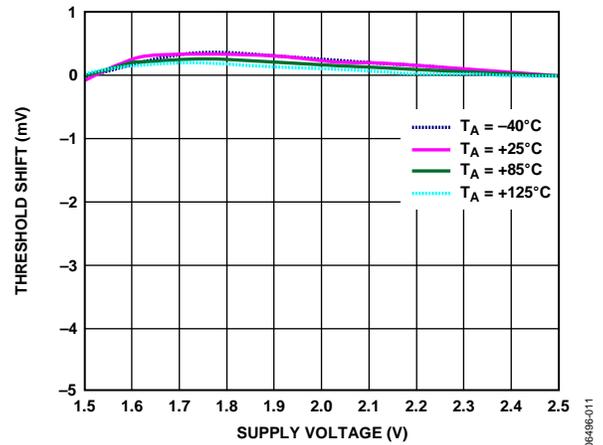


Figure 14. Minimum Supply Voltage

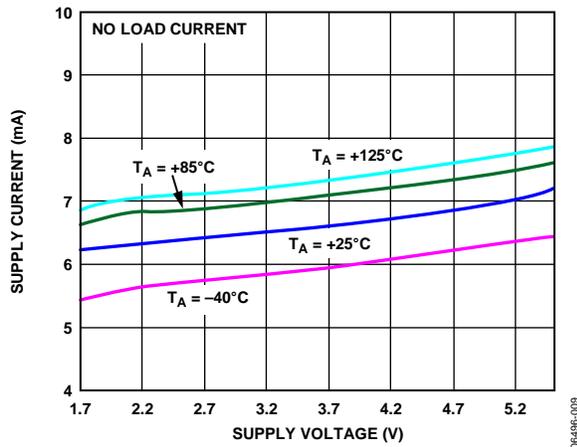


Figure 12. Quiescent Supply Current vs. Supply Voltage

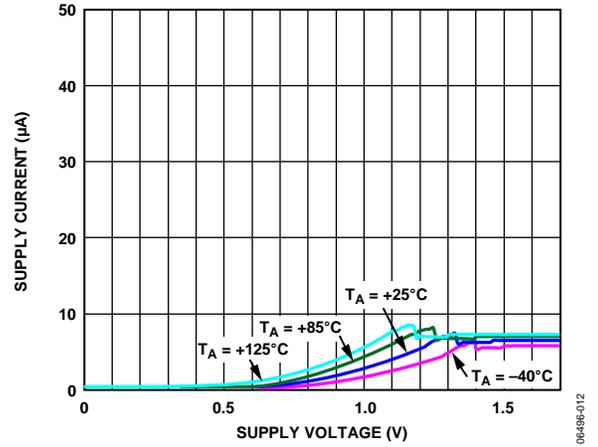


Figure 15. Start-Up Supply Current

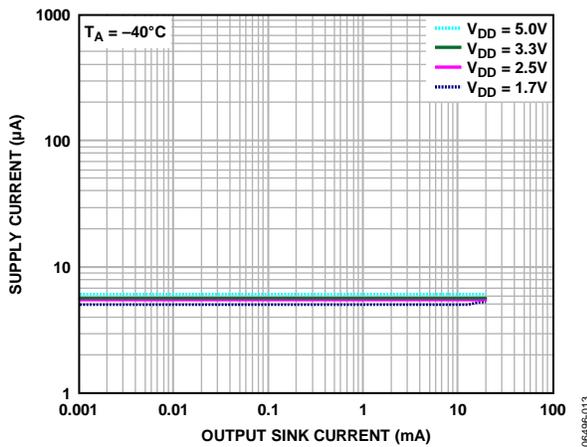


Figure 13. Supply Current vs. Output Sink Current

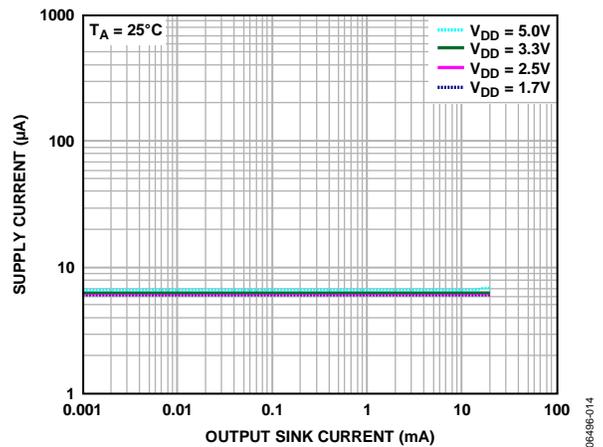


Figure 16. Supply Current vs. Output Sink Current

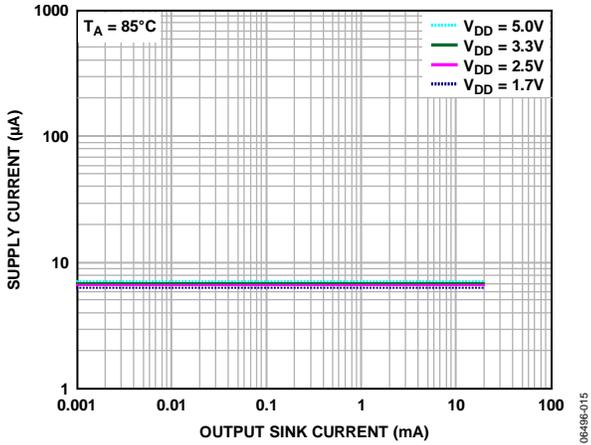


Figure 17. Supply Current vs. Output Sink Current

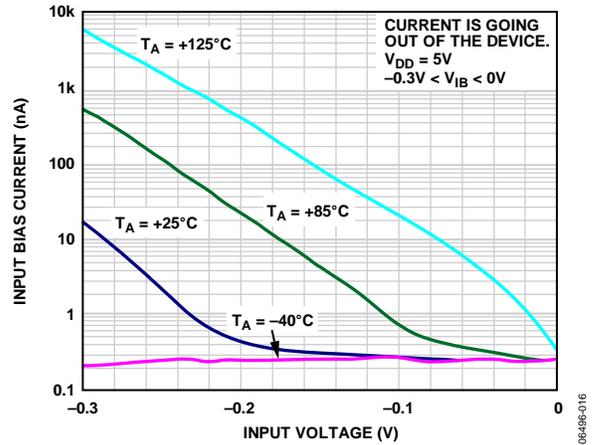


Figure 20. Below Ground Input Bias Current

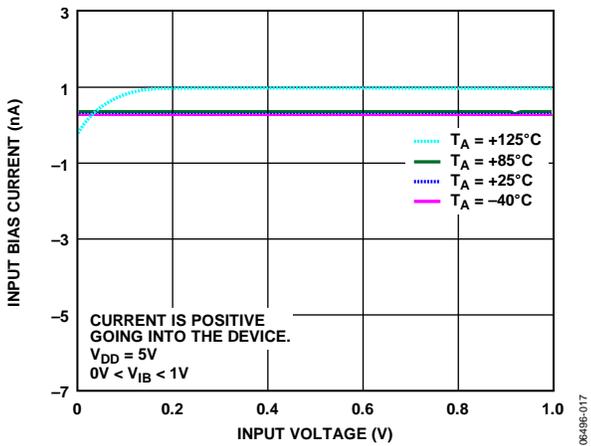


Figure 18. Low Level Input Bias Current

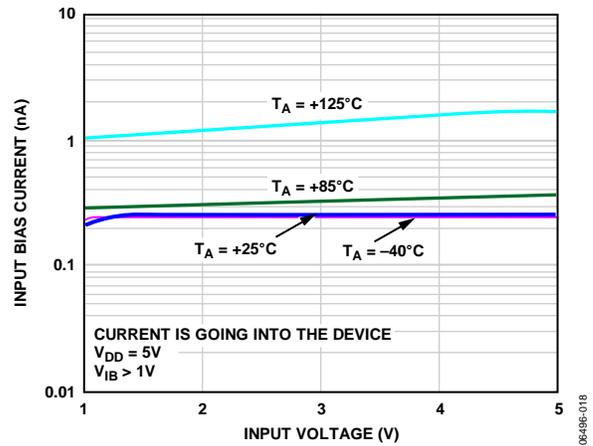


Figure 21. High Level Input Bias Current

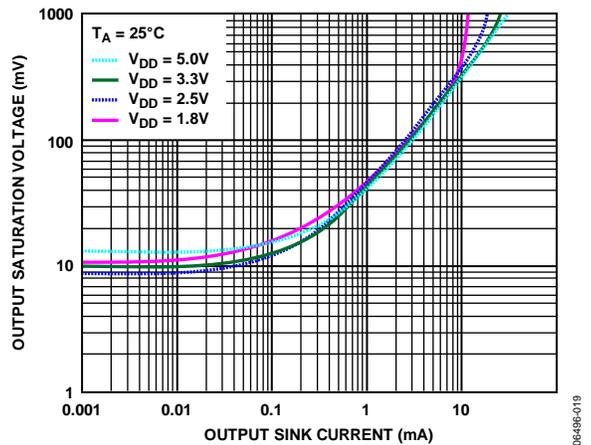


Figure 19. Output Saturation Voltage vs. Output Sink Current

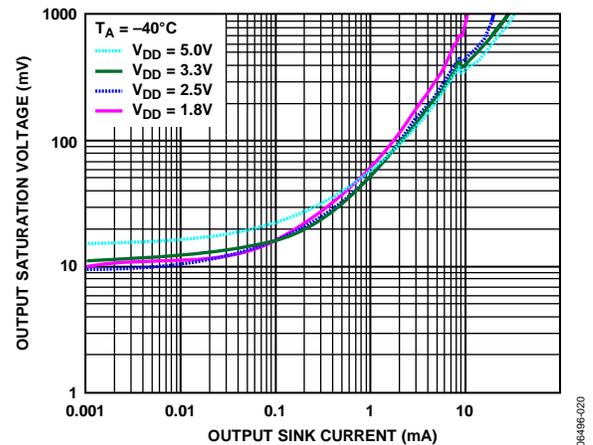


Figure 22. Output Saturation Voltage vs. Output Sink Current

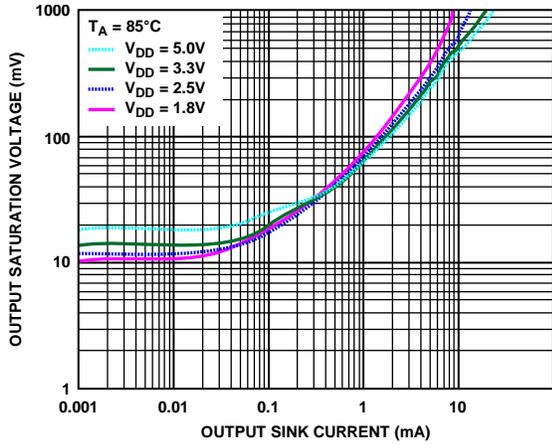


Figure 23. Output Saturation Voltage vs. Output Sink Current

06496-021

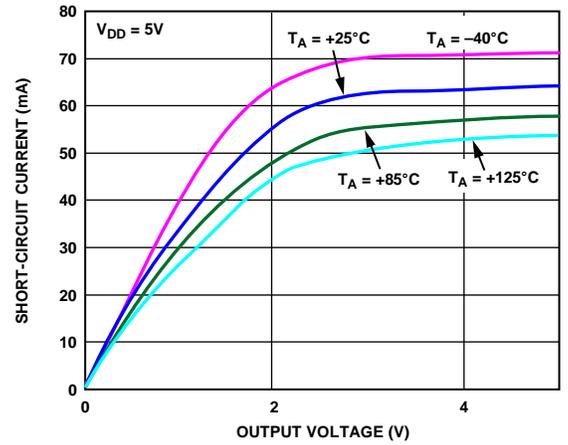


Figure 26. Short-Circuit Current vs. Output Voltage

06496-022

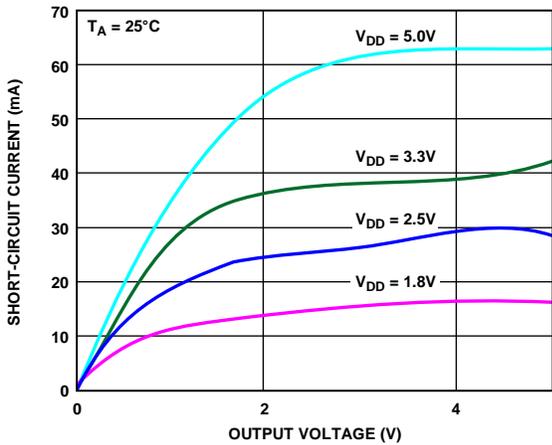


Figure 24. Short-Circuit Current vs. Output Voltage

06496-023

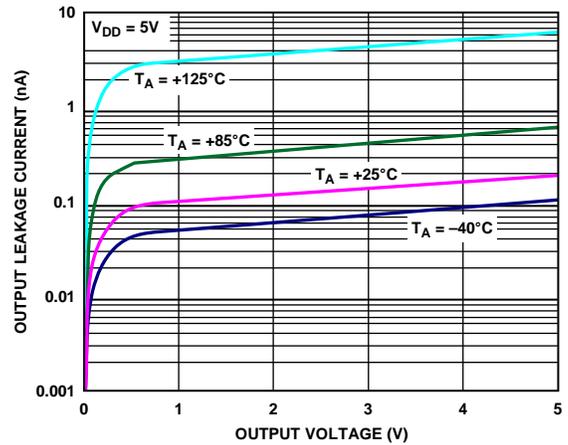


Figure 27. Output Leakage Current vs. Output Voltage

06496-024

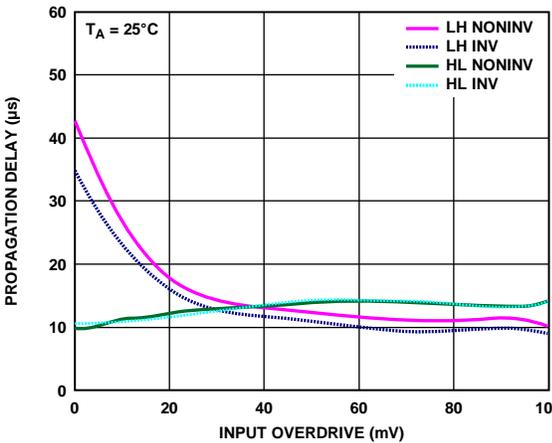


Figure 25. Propagation Delay vs. Input Overdrive

06496-025

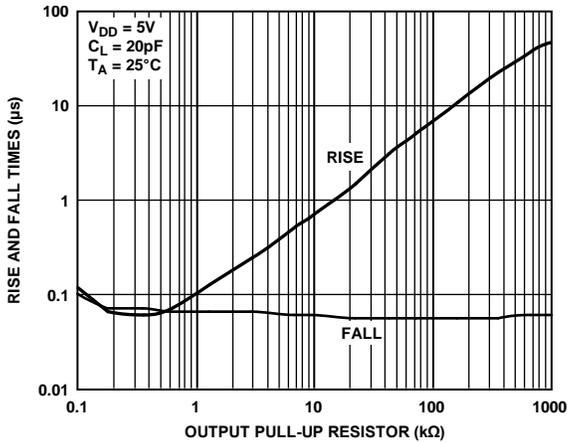


Figure 28. Rise and Fall Times vs. Output Pull-Up Resistor

06496-027

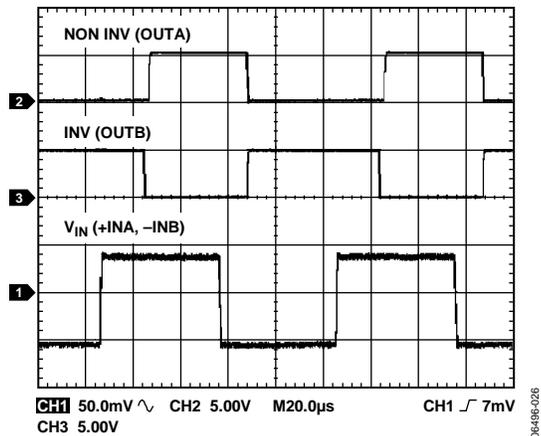


Figure 29. Noninverting and Inverting Comparators Propagation Delay

APPLICATION INFORMATION

The **ADCMP361** is a low power comparator and reference circuit featuring a 400 mV reference that operates from 1.7 V to 5.5 V. The comparator is 0.275% accurate with a built-in hysteresis of 9.3 mV. There are two outputs, one the inverse of the other. This enables the **ADCMP361** to be used as an inverting or a noninverting comparator circuit. These open-drain outputs are capable of sinking 40 mA.

COMPARATORS AND INTERNAL REFERENCE

The comparator has one input available externally; the other comparator input is connected internally to the 400 mV reference. The rising input threshold voltage of the comparators is designed to be equal to that of the reference.

POWER SUPPLY

The **ADCMP361** is designed to operate from 1.7 V to 5.5 V. A 100 nF decoupling capacitor is recommended between V_{DD} and GND.

INPUTS

The comparator input is limited to the maximum V_{DD} voltage range. The voltage on these inputs can be above V_{DD} but never above the maximum allowed V_{DD} voltage. When adding a resistor string to the input, take care when choosing resistor values. This is due to the fact that the input bias current will be in parallel with the bottom resistor, R_2 , of the input resistor divider string. This bottom resistor must therefore be chosen carefully in order to reduce the error introduced by this bias current (see Figure 30).

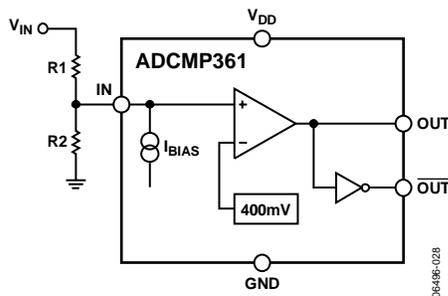


Figure 30. Input Bias Current Effect on Input Resistor String

OUTPUTS

The open-drain comparator outputs are limited to the maximum specified V_{DD} voltage range, regardless of the V_{DD} voltage. These outputs are capable of sinking up to 40 mA.

ADDING HYSTERESIS

To prevent oscillations at the output caused by noise or slowly moving signals passing the switching threshold, each comparator has built-in hysteresis of approximately 9.3 mV. Positive feedback can be used to increase hysteresis.

For the configuration shown in Figure 31, two resistors are used to create different switching thresholds, depending on whether the input signal is increasing or decreasing in magnitude. When

the input voltage is increasing, the threshold is above V_{REF} , and when it is decreasing, the threshold is below V_{REF} . V_{IN_HI} is the high input threshold used to trigger the output low to high transmission. V_{IN_LO} is the low input threshold used to trigger the output high to low transmission.

The upper input threshold level is given by

$$V_{IN_HI} = \frac{V_{REF}(R1 + R2)}{R2}$$

assuming $R_{LOAD} \gg R2, R_{PULLUP}$ where $V_{REF} = 0.4$ V.

The lower input threshold level is given by

$$V_{IN_LO} = \frac{V_{REF}(R1 + R2 + R_{PULLUP}) - V_{CC}R1}{R2 + R_{PULLUP}}$$

The hysteresis is the difference between these voltage levels and is given by

$$\Delta V_{IN} = \frac{V_{CC}R1}{R2 + R_{PULLUP}}$$

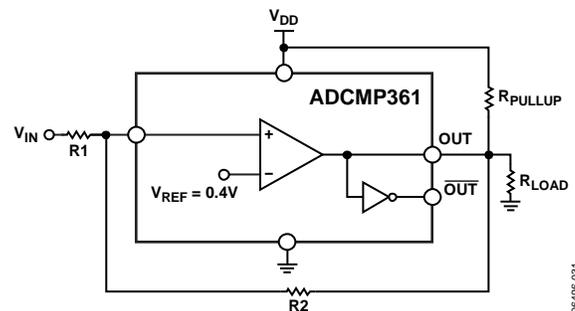


Figure 31. Comparator Configuration with Added Hysteresis

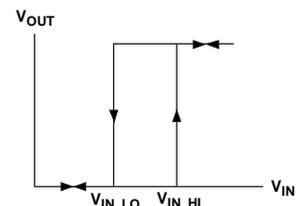
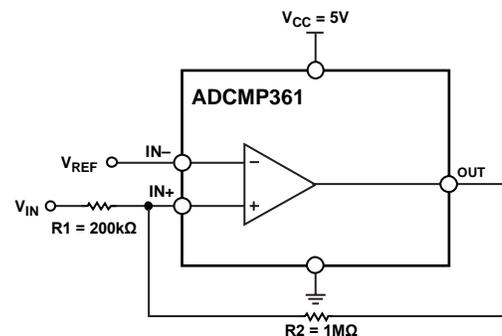
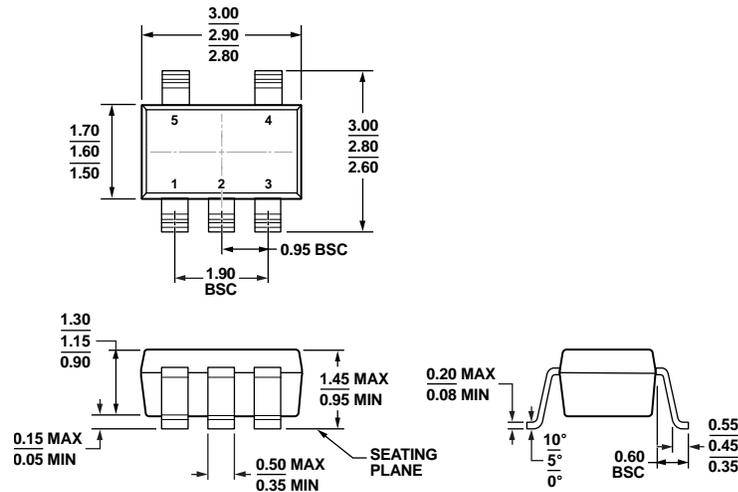


Figure 32. Noninverting Comparator Configuration with Hysteresis

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-178-AA

Figure 33. 5-Lead Small Outline Transistor Package [SOT-23] (RJ-5)

Dimensions shown in millimeters

11-01-2016-A

ORDERING GUIDE

| Model ^{1, 2} | Temperature Range | Package Description | Package Option | Branding |
|-----------------------|-------------------|---------------------|----------------|----------|
| ADCMP361YRJZ-REEL7 | -40°C to +125°C | 5-Lead SOT-23 | RJ-5 | M99 |
| ADCMP361WRJZ-RL7 | -40°C to +125°C | 5-Lead SOT-23 | RJ-5 | M99 |

¹ Z = RoHS Compliant Part.² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The ADCMP361W models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.